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VS-20ETS08FP-M3, VS-20ETS12FP-M3

Vishay Semiconductors

High Voltage, Input Rectifier Diode, 20 A



2L TO-220 FullPAK

PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V _R	800 V, 1200 V			
V _F at I _F	1.1 V			
I _{FSM}	300 A			
T _J max.	150 °C			
Package	2L TO-220 FullPAK			
Circuit configuration	Single			

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47



COMPLIANT HALOGEN

- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS		
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	18	22	A		

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	20	А		
V _{RRM}	Range	800, 1200	V		
I _{FSM}		300	А		
V _F	10 A, T _J = 25 °C	1.0	V		
TJ		-40 to +150	°C		

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-20ETS08FP-M3	800	900	1			
VS-20ETS12FP-M3	1200	1300	I			

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 51 \ ^{\circ}C$, 180° conduction half sine wave	20	
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V_{RRM} applied	250	A
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	300	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	316	– A ² s
		10 ms sine pulse, no voltage reapplied	442	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	T _{.1} = 150 °C		10.4	mΩ
Threshold voltage	V _{F(TO)}			0.85	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA
		T _J = 150 °C	VR - naieu VRRM	1.0	ШA

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage tempera	ture range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.8	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque minimaxi				6.0 (5.0)	kgf ⋅ cm
				12 (10)	(lbf \cdot in)
Marking device				20ETS	08FP
			Case style 2L TO-220 FullPAK	20ETS	S12FP



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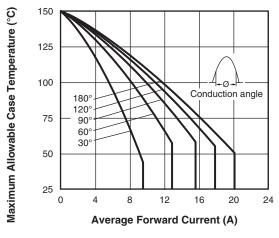


Fig. 1 - Current Rating Characteristics

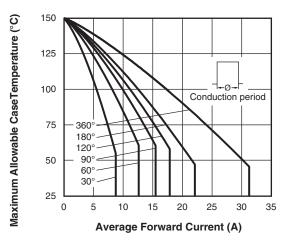


Fig. 2 - Current Rating Characteristics

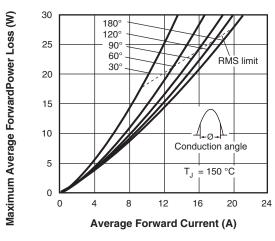


Fig. 3 - Forward Power Loss Characteristics

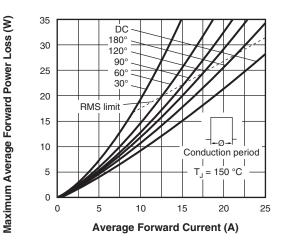
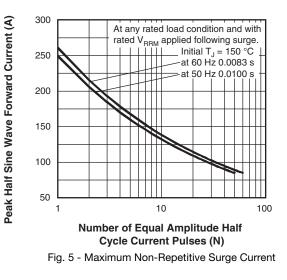


Fig. 4 - Forward Power Loss Characteristics



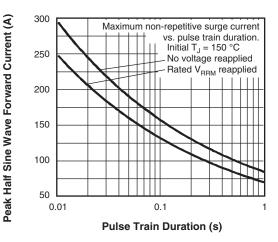


Fig. 6 - Maximum Non-Repetitive Surge Current

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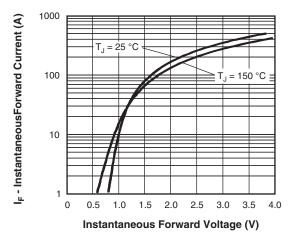


Fig. 7 - Forward Voltage Drop Characteristics

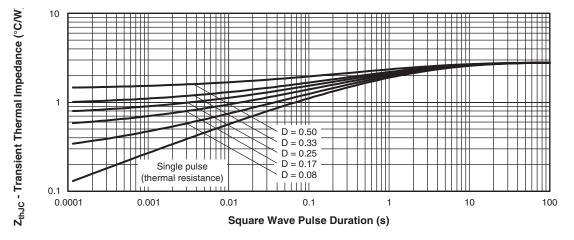
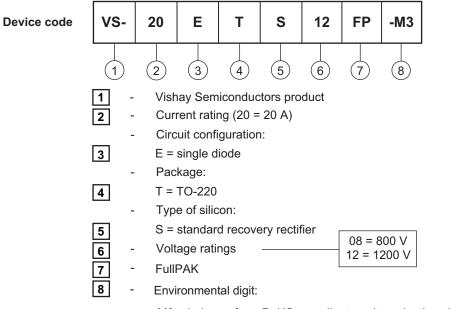


Fig. 8 - Thermal Impedance ZthJC Characteristics



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ORDERING INFORMATION TABLE



-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPT				
VS-20ETS08FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETS12FP-M3	50	1000	Antistatic plastic tubes		

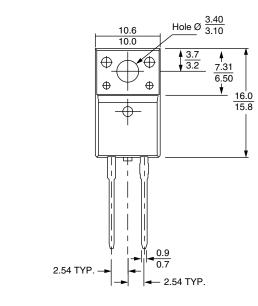
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

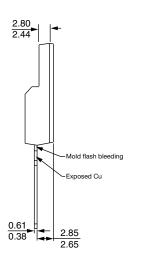


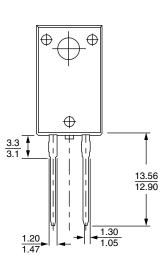
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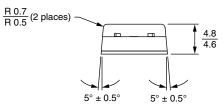
DIMENSIONS in millimeters







Bottom view





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